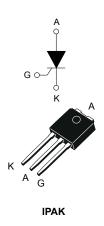


## 4 A Sensitive gate SCR in IPAK package



#### **Features**

- 4 A SCR
- Sensitive SCR: I<sub>GT</sub> = 200 μA
- $V_{DRM}$  /  $V_{RRM}$  = 600 V and  $V_{DSM}$  /  $V_{RSM}$  = 750 V
- 125  $^{\circ}$ C maximum junction temperature  $T_{j}$
- IPAK package
- · Halogen-free molding, lead-free plating
- ECOPACK2 compliant

### **Applications**

- Actuators
- Ignitors
- Inrush current limiting circuits

# Product status link X0402MH

Product summary		
I <sub>T(RMS)</sub>	4 A	
V <sub>DSM</sub> /V <sub>RSM</sub>	750 V	
I <sub>GT</sub>	200 μΑ	
T <sub>j</sub> max.	125 °C	

## **Description**

The X04 series is 4 A SCR housed in compact through hole IPAK package. This highly sensitive device is suited to home appliances or power tools and industrial systems and drives loads up to 4 A.



## 1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Value	Unit	
I <sub>T(RMS)</sub>	RMS on-state current (full sine wave)	T <sub>c</sub> = 114 °C	4	А
I <sub>T AV</sub>	RMS on-state average current (full sine wave)	T <sub>c</sub> = 114 °C	2.5	А
l	Non repetitive surge peak on-state current (full cycle,	t = 8.3 ms	33	Δ.
I <sub>TSM</sub>	T <sub>j</sub> initial = 25 °C)	t = 10 ms	30	Α
I <sup>2</sup> t	I <sup>2</sup> t value for fusing	t <sub>p</sub> = 10 ms	9	A <sup>2</sup> s
dl/dt	Critical rate of rise of on-state current, $I_G$ = 2 x $I_{GT}$ , tr $I_g$ = 125 °C $I_{GT}$		50	A/µs
V <sub>DRM</sub> /V <sub>RRM</sub>	Repetitive peak off-state voltage $T_j$ = 125 °C		600	V
V <sub>DSM</sub> /V <sub>RSM</sub>	Non Repetitive peak off-state voltage, 10 ms	750	V	
I <sub>GM</sub>	Maximum peak gate current	t <sub>D</sub> = 20 μs, T <sub>i</sub> = 125 °C	1.2	Α
P <sub>GM</sub>	Maximum gate power dissipation	0.5	W	
T <sub>stg</sub>	Storage temperature range	-40 to +125	°C	
Tj	Operating junction temperature range		-40 to +125	°C
TL	Maximum lead temperature for soldering during 10 s		260	°C

Table 2. Electrical characteristics ( $T_j$  = 25 °C, unless otherwise specified)

Symbol	Test con	Value	Unit		
I <sub>GT</sub> <sup>(1)</sup>	$V_D = 12 \text{ V}, R_L = 140 \Omega$	V = 42 V B = 140 O		200	μΑ
V <sub>GT</sub>	ν <sub>D</sub> = 12 ν, 1\(\(\text{L} = 140 \)2		Max.	0.8	V
$V_{GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 125 ^{\circ}\text{C}$		Min.	0.1	V
$V_{RGM}$	I <sub>RG</sub> = 10 μA		Max.	8	V
IL	$I_G = 1.2 \times I_{GT}$		Max.	6	mA
I <sub>H</sub> (2)	$I_T$ = 500 mA, gate open		Max.	5	mA
dV/dt (2)	$V_D$ = 67 % $V_{DRM}$ , $R_{GK}$ = 1 k $\Omega$ $T_j$ = 110 °C		Min.	10	V/µs

<sup>1.</sup> For both polarities of OUT pin referenced to COM pin.

**Table 3. Static characteristics** 

Symbol	Test conditions	Tj		Value	Unit
V <sub>TM</sub> <sup>(1)</sup>	I <sub>TM</sub> = 8 A, t <sub>p</sub> = 380 μs	25 °C	Max.	1.8	V
V <sub>TO</sub> (1)	Threshold voltage	125 °C	Max.	0.85	V
R <sub>D</sub> <sup>(1)</sup>	Dynamic resistance	125 °C	Max.	100	mΩ
I <sub>DRM</sub> /I <sub>RRM</sub>	$V_D = V_{DRM}$ ; $V_R = V_{RRM}$ ; $R_{GK} = 1 \text{ k}\Omega$	25 °C	Max.	5	μA
		125°C		1	mA

<sup>1.</sup> For both polarities of A2 referenced to A1.

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<sup>2.</sup> For both polarities of A2 referenced to A1.



#### Table 4. Thermal resistance

Symbol	Parameter		Value	Unit
R <sub>th(j-c)</sub>	Junction to case (DC)	Max.	3	°C/W
$R_{th(j-a)}$	Junction to ambient	Тур.	70	°C/W

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### 1.1 Characteristics (curves)

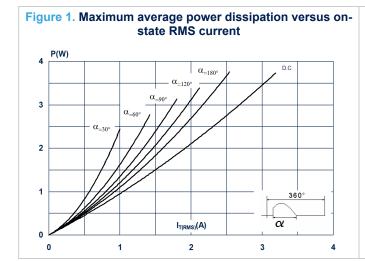
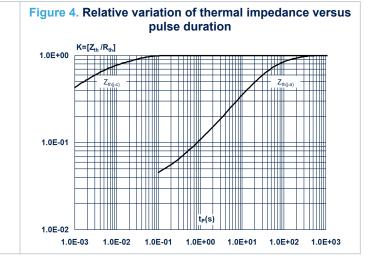
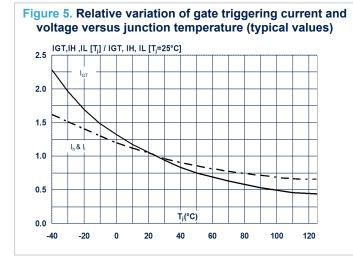
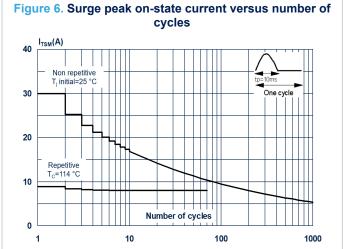


Figure 2. Average and DC on-state current versus case temperature  $\begin{bmatrix} 1_{\mathsf{T(AY)}}(\mathsf{A}) \\ 1_{\mathsf{T(AY)}}(\mathsf{A}) \\ 1_{\mathsf{C}} \\ 1_{\mathsf{C}}$ 







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Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse with width  $t_{\rm p}$  < 10 ms and corresponding value of  $l^2t$ 

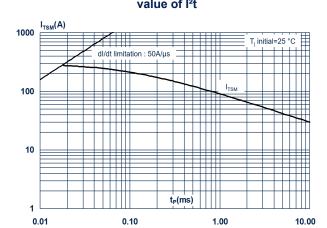


Figure 8. On-state characteristics (maximum values)

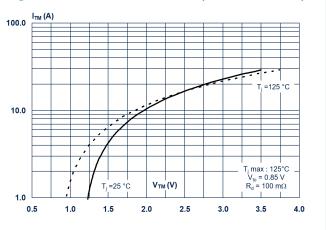


Figure 9. Relative variation of static dV/dt immunity versus gate-to-cathode resistance (typical values)

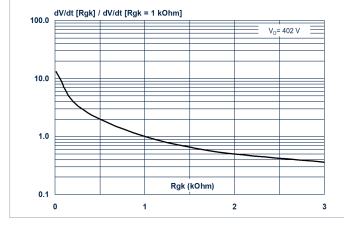


Figure 10. Relative variation of static dV/dt immunity versus gate-to-cathode capacitance (typical values)

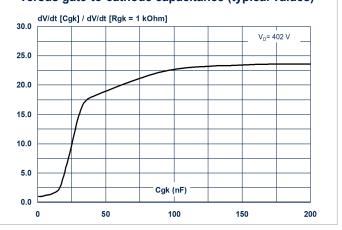
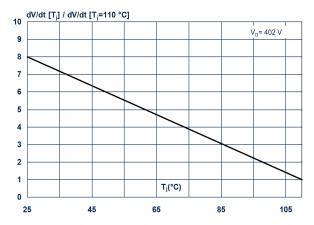


Figure 11. Relative variation of static dV/dt immunity versus junction temperature



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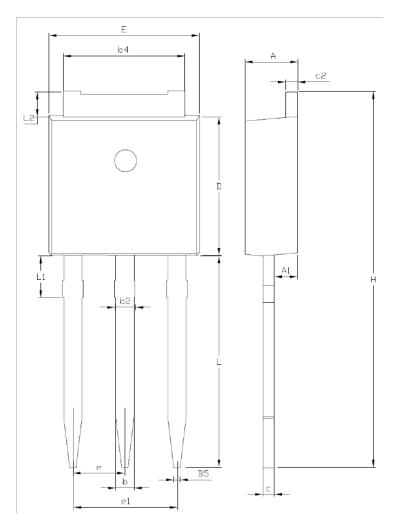
# 2 Package information

To meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

#### 2.1 IPAK package information

- Molding compouned resin is halogen free and meets UL94 flammability standard, level V0
- Lead-free package leads plating

Figure 12. IPAK package outline



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Table 5. IPAK package mechanical data

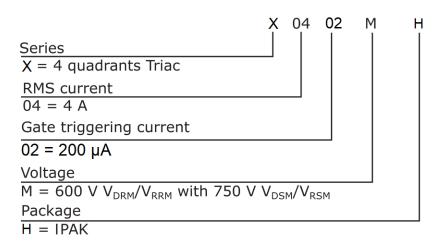
	Dimensions						
Ref.	MillimetersInches (for reference only)						
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А	2.20		2.40	0.086		0.094	
A1	0.90		1.10			0.035	
b	0.64		0.90	0.025		0.035	
b2			0.95			0.037	
b4	5.20		5.43				
B5		0.30			0.012		
С	0.45		0.60				
c2	0.46		0.60				
D	6		6.20				
E	6.40		6.65	0.252		0.262	
е		2.28			0.090		
e1	4.40		4.60	0.173		0.181	
Н		16.10			0.634		
L	9		9.60	0.354		0.377	
L1	0.8		1.20	0.031		0.047	
L2		0.80	1.25		0.031	0.049	
V1		10°			10°		

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# 3 Ordering information

Figure 13. Ordering information scheme



**Table 6. Ordering information** 

Order code	Marking	Package	Weight	Base qty.	Delivery mode
X0402MH	X0402MH	IPAK	0.31 g	75	Tube

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## **Revision history**

Table 7. Document revision history

Date	Revision	Changes
06-Sep-2022	1	Initial release.
09-Dec-2024	2	Updated Section IPAK package silhouette.

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